NSN 5962-01-393-7837

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View Online at https://aerobasegroup.com/nsn/5962-01-393-7837

	Body Length:
	Between 0.742 inches and 0.758 inches
	Body Width:
	Between 0.442 inches and 0.458 inches
	Body Height:
	Between 0.077 inches and 0.093 inches
	Maximum Power Dissipation Rating:
	1.0 watts
	Operating Tempurature Range:
	-55.0/+125.0 degrees celsius
	Storage Tempurature Range:
	-65.0/+150.0 degrees celsius
	Features Provided:
,	W/enable and w/disable
	Inclosure Material:
	Ceramic
	Inclosure Configuration:
	Leadless flat pack
	Output Logic Form:
	Complementary-metal oxide-semiconductor logic
	Input Circuit Pattern:
	21 input
	Current Rating Per Characteristic:
	125.00 milliamperes reverse current, dc absolute
•	Terminal Surface Treatment:
	Solder
,	Voltage Rating And Type Per Characteristic:
	-1.0 volts power source and 7.0 volts power source
	Time Rating Per Chacteristic:
	35.00 nanoseconds access
	Memory Device Type:
	Ram
	Test Data Document:
	96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.)
	Terminal Type And Quantity:

32 leadless

Shelf Life:

Sileii

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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